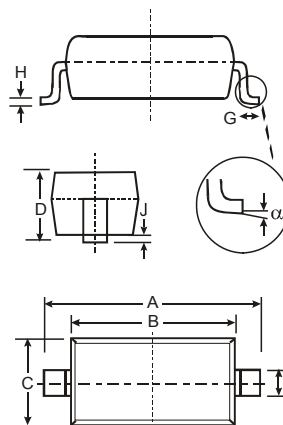


### Features

- Fast Switching Speed.
- General Purpose Rectification.
- Silicon Epitaxial Planar Construction.
- Marking Code:W1



SOD-123		
Dim	Min	Max
A	3.55	3.85
B	2.55	2.85
C	1.40	1.70
D	—	1.35
E	0.45	0.65
	0.55 Typical	
G	0.25	—
H	0.11 Typical	
J	—	0.10
$\alpha$	0°	8°
All Dimensions in mm		

### Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	$V_{RM}$	100	V
Reverse Voltage	$V_R$	80	V
Average Rectified Forward Current	$I_{F(AV)}$	150	mA
Non-repetitive Peak Forward Surge Current at $t = 1 \mu\text{s}$	$I_{FSM}$	4	A
Power Dissipation	$P_{tot}$	400	mW
Thermal Resistance from Junction to Ambient Air	$R_{\theta JA}$	312	$^\circ\text{C/W}$
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 150	$^\circ\text{C}$

### Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 5 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 100 \text{ mA}$ at $I_F = 150 \text{ mA}$	$V_F$	0.62 - - -	0.72 0.855 1 1.25	V
Reverse Leakage Current at $V_R = 80 \text{ V}$ at $V_R = 20 \text{ V}$ at $V_R = 75 \text{ V}, T_J = 150^\circ\text{C}$ at $V_R = 25 \text{ V}, T_J = 150^\circ\text{C}$	$I_R$	- - - -	100 25 50 30	nA nA $\mu\text{A}$ $\mu\text{A}$
Reverse Breakdown Voltage at $I_R = 100 \mu\text{A}$	$V_{(BR)R}$	80	-	V
Total Capacitance at $V_R = 0.5 \text{ V}, f = 1 \text{ MHz}$	$C_{tot}$	-	4	pF
Reverse Recovery Time at $I_F = I_R = 10 \text{ mA}, I_{tr} = 0.1 \times I_R, R_L = 100 \Omega$	$t_{rr}$	-	4	ns

### TYPICAL TRANSIENT CHARACTERISTICS

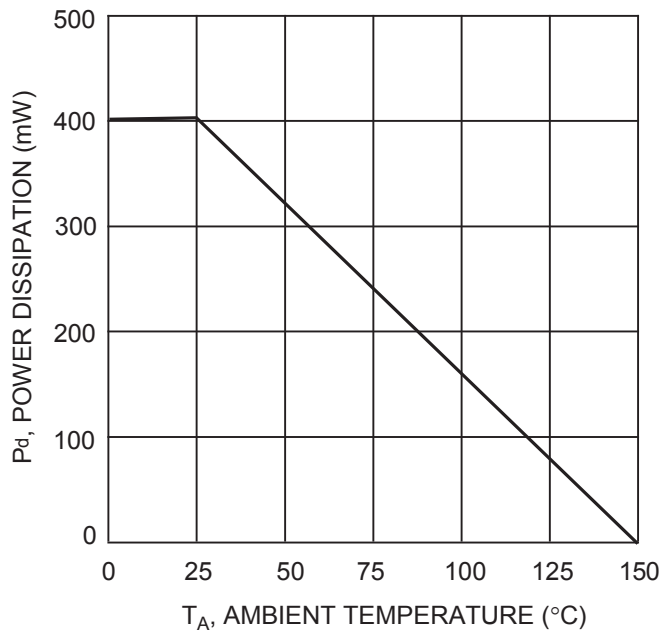


Fig. 1 Power Derating Curve

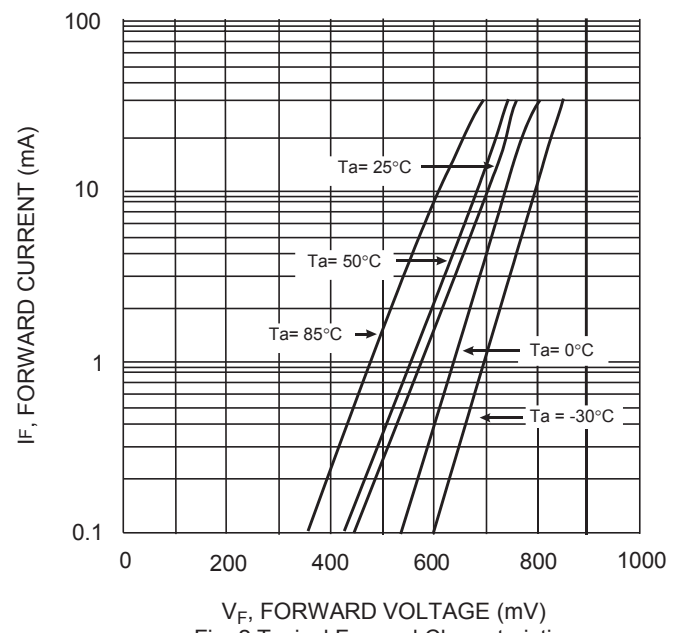


Fig. 2 Typical Forward Characteristics

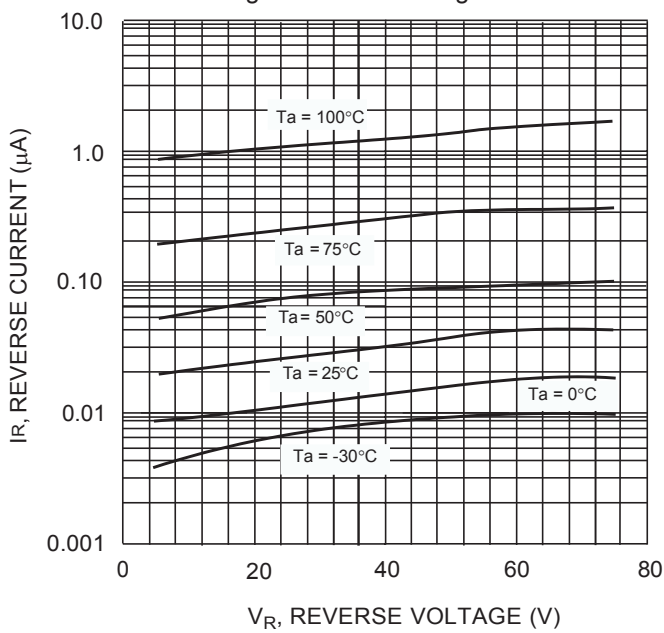


Fig. 3 Typical Reverse Characteristics

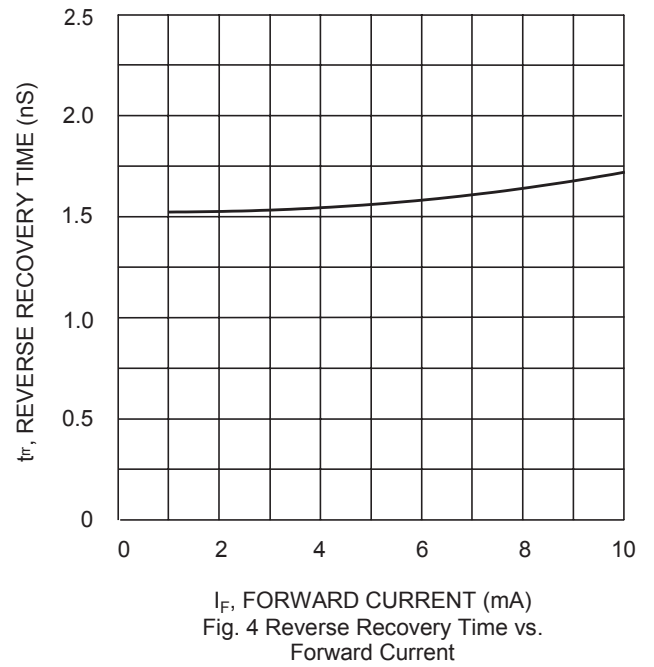


Fig. 4 Reverse Recovery Time vs. Forward Current

---

## **IMPORTANT NOTICE**

---

HC-SEMI reserves the right to make changes without further notice to any products herein.

HC-SEMI makes no warranty, representation or guarantee regarding

The suitability of its products for any particular purpose, nor does HC-SEMI assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages.

“Typical” parameters can and do vary in different applications. All operating parameters, including “Typicals” must be validated for each customer application by customer’s technical experts.

HC-SEMI products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the HC-SEMI product could create a situation where personal injury or death may occur.

Should Buyer purchase or use HC-SEMI products for any such unintended or unauthorized application, Buyer shall indemnify and hold HC-SEMI and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that HC-SEMI was negligent regarding the design or manufacture of the part.